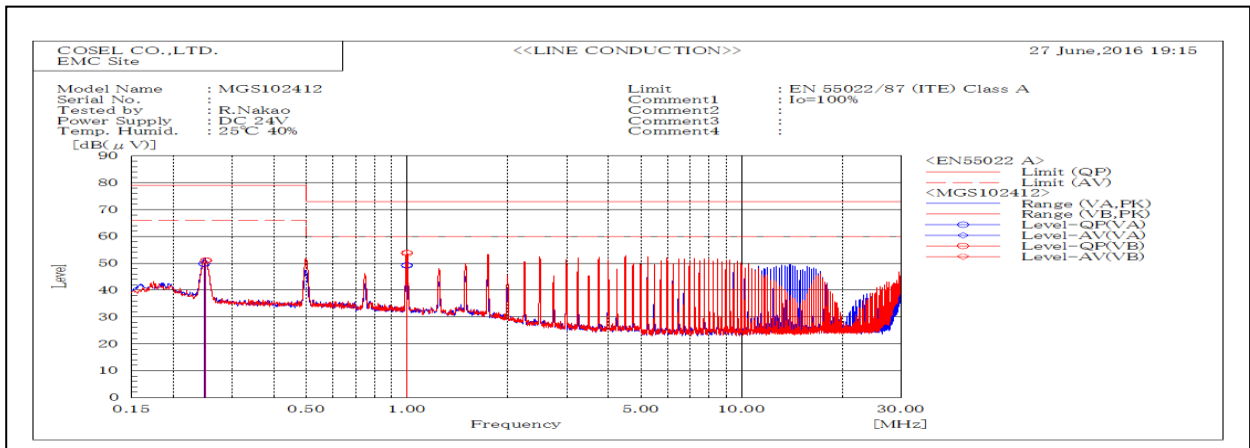
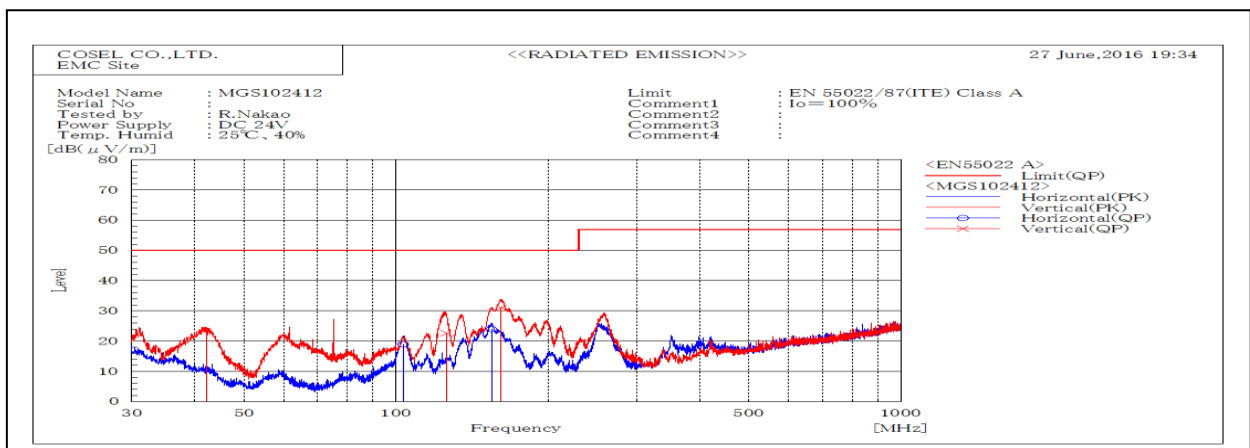


DATA SHEET		Date	15-Jul-16
Model	MGS102412	Temp.	25 degreeC
Test	EMI Line conduction & Radiated emission	Humid.	40 %RH
		Tested by	R.Nakao



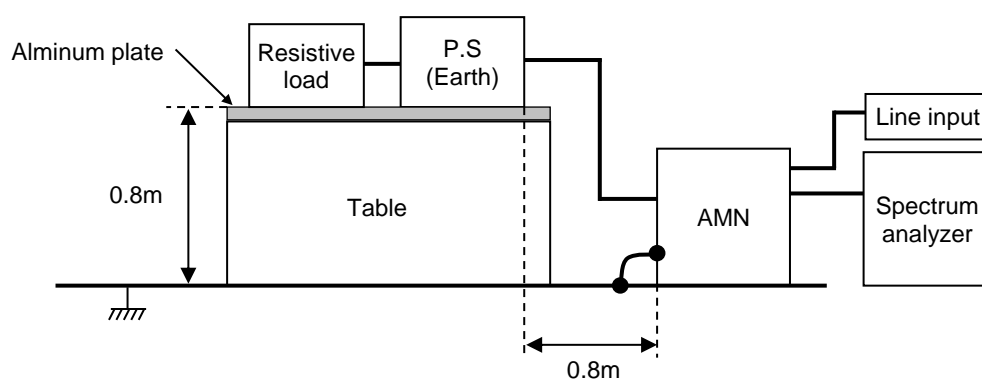
Frequency MHz	Harm	Line Phase	Reading dB(μV)		Factor dB	Level dB(μV)		Limit dB(μV)		Margin dB		Pass/ Fail	Remark
			QP	AV		QP	AV	QP	AV	QP	AV		
0.2471		VA	29.8	29.7	20.0	49.8	49.7	79	66	29.2	16.3	Pass	
0.25007		VB	31.1	30.9	20.0	51.1	50.9	79	66	27.9	15.1	Pass	
0.99839		VA	29.3	29.3	19.9	49.2	49.2	73	60	23.8	10.8	Pass	
0.99754		VB	33.9	34.1	19.9	53.8	54.0	73	60	19.2	6.0	Pass	



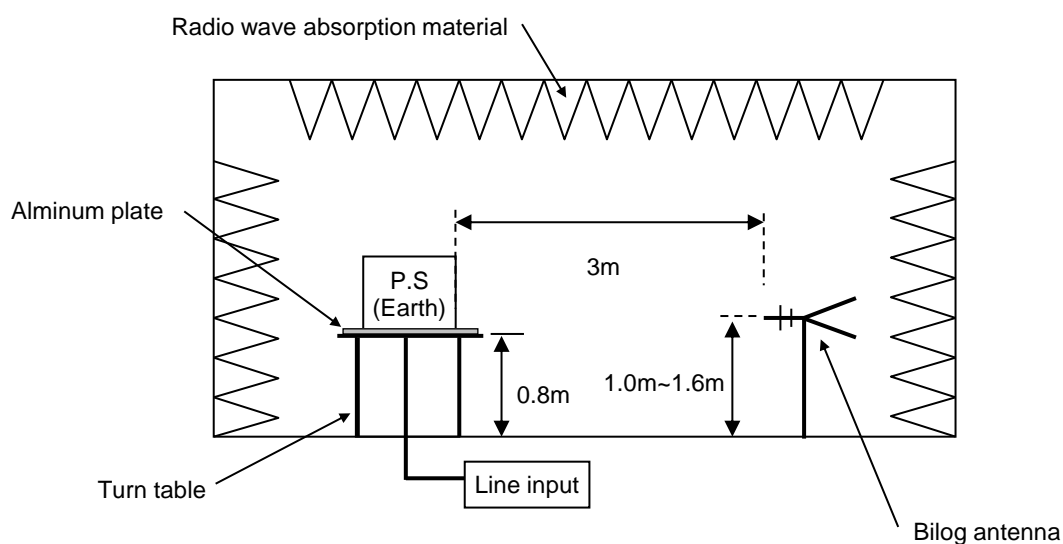
Frequency MHz	Polarization	Stability	Reading dB(μV)	Limit dB(μV/m)	Margin dB(μV/m)	Pass/Fail	Height cm	Angle deg	Remark
			QP	QP	QP				
42.151	V	Stable	23.4	50.0	26.6	Pass	105	149	
103.341	H	Stable	19.0	50.0	31.0	Pass	155	247	
125.956	V	Stable	22.6	50.0	27.4	Pass	111	347	
154.563	H	Stable	24.0	50.0	26.0	Pass	152	243	
161.500	V	Stable	31.1	50.0	18.9	Pass	109	342	

DATA SHEET		Date	15-Jul-16
Model	Circuit used for measurement	Temp.	25 degreeC
Test	EMI Line conduction & Radiated emission	Humid.	40 %RH
		Tested by	R.Nakao

1. Line conduction



2. Radiated emission

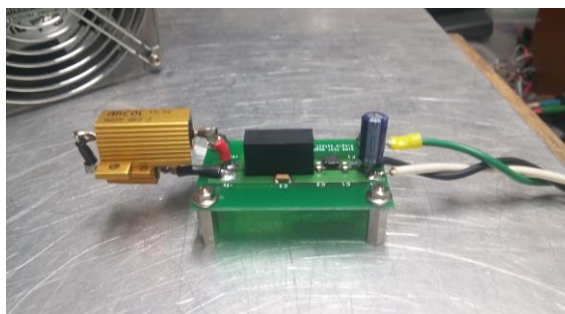


Conditions

Test : EMI
Model Name : MGS10□□

○Photographs of Test Set-Up

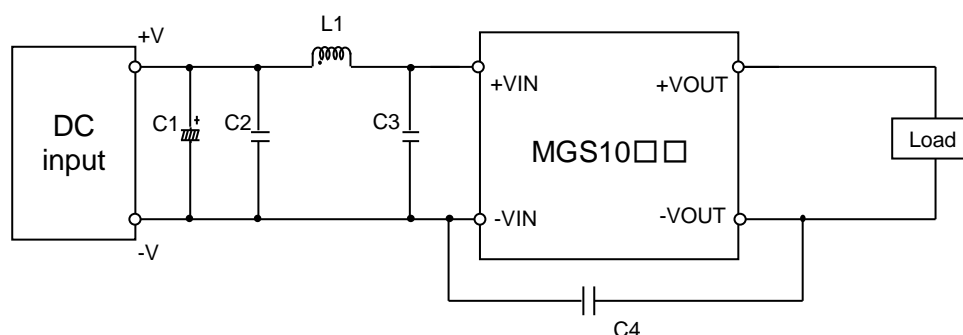
LINE CONDUCTION



RADIATED EMISSION



○Testing circuitry



C1 :	MGS1005□□	25V 470 μ F	Electric capacitor (LXZseries NIPPON CHEMI-CON)
	MGS1012□□	50V 100 μ F	Electric capacitor (LXZseries NIPPON CHEMI-CON)
	MGS1024□□	50V 100 μ F	Electric capacitor (LXZseries NIPPON CHEMI-CON)
	MGS1048□□	100V 39 μ F	Electric capacitor (LXVseries NIPPON CHEMI-CON)
C2 :	MGS1005□□	16V 22 μ F	Ceramic capacitor (GRM31CC71C226K MURATA MANUFACTURING)
	MGS1012□□	25V 10 μ F	Ceramic capacitor (GRM31CR71E106K MURATA MANUFACTURING)
	MGS1024□□	50V 4.7 μ F	Ceramic capacitor (GRM31CR71H475K MURATA MANUFACTURING)
	MGS1048□□	100V 2.2 μ F	Ceramic capacitor (GRM31CC72A225K MURATA MANUFACTURING)
C3 :	MGS1005□□	—	
	MGS1012□□	25V 10 μ F	Ceramic capacitor (GRM31CR71E106K MURATA MANUFACTURING)
	MGS1024□□	50V 4.7 μ F	Ceramic capacitor (GRM31CR71H475K MURATA MANUFACTURING)
	MGS1048□□	100V 2.2 μ F	Ceramic capacitor (GRM31CC72A225K MURATA MANUFACTURING)
C4 :	MGS1005□□	2kV 1000pF	Ceramic capacitor (GR442QR73D102K MURATA MANUFACTURING)
	MGS1012□□	2kV 1000pF	Ceramic capacitor (GR442QR73D102K MURATA MANUFACTURING)
	MGS1024□□	2kV 1000pF	Ceramic capacitor (GR442QR73D102K MURATA MANUFACTURING)
	MGS1048□□	2kV 2200pF	Ceramic capacitor (GR443QR73D222K MURATA MANUFACTURING)
L1 :	MGS1005□□	3000mA 1.5 μ H	Inductor(LQH5BPN1R5NT0 MURATA MANUFACTURING)
	MGS1012□□	2600mA 2.2 μ H	Inductor(LQH5BPN2R2NT0 MURATA MANUFACTURING)
	MGS1024□□	1600mA 10 μ H	Inductor(LQH5BPN100MT0 MURATA MANUFACTURING)
	MGS1048□□	1050mA 22 μ H	Inductor(LQH5BPN220MT0 MURATA MANUFACTURING)